

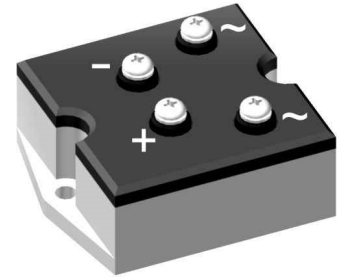
Standard Rectifier Module


| | |
|-------------------------|-------|
| 1~ Rectifier | |
| $V_{RRM} =$ | 800 V |
| $I_{DAV} =$ | 45 A |
| $I_{FSM} =$ | 750 A |

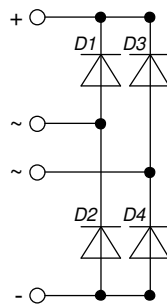
1~ Rectifier Bridge

Part number

VBO50-08NO7



 E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For one phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: PWS-B

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Easy to mount with two screws
- Base plate: Aluminium internally DCB isolated
- Advanced power cycling

Disclaimer Notice

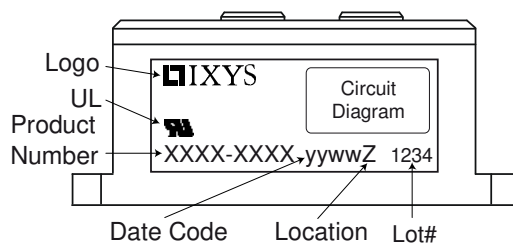
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| Rectifier | | | | Ratings | | | |
|------------|--|---|---|--------------------------|------|------|-------------------|
| Symbol | Definition | Conditions | | min. | typ. | max. | Unit |
| V_{RSM} | max. non-repetitive reverse blocking voltage | | | | | 900 | V |
| V_{RRM} | max. repetitive reverse blocking voltage | | | | | 800 | V |
| I_R | reverse current | $V_R = 800\text{ V}$ | $T_{VJ} = 25^\circ\text{C}$ | | | 100 | μA |
| | | $V_R = 800\text{ V}$ | $T_{VJ} = 150^\circ\text{C}$ | | | 1.5 | mA |
| V_F | forward voltage drop | $I_F = 20\text{ A}$ | $T_{VJ} = 25^\circ\text{C}$ | | | 1.03 | V |
| | | $I_F = 40\text{ A}$ | | | | 1.14 | V |
| | | $I_F = 20\text{ A}$ | $T_{VJ} = 125^\circ\text{C}$ | | | 0.92 | V |
| | | $I_F = 40\text{ A}$ | | | | 1.06 | V |
| I_{DAV} | bridge output current | $T_C = 85^\circ\text{C}$ rectangular | $T_{VJ} = 150^\circ\text{C}$ d = 0.5 | | | 45 | A |
| V_{F0} | threshold voltage | } for power loss calculation only | | | | 0.76 | V |
| r_F | slope resistance | | | | | 6.9 | m Ω |
| R_{thJC} | thermal resistance junction to case | | | | | 2.7 | K/W |
| R_{thCH} | thermal resistance case to heatsink | | | | 0.4 | | K/W |
| P_{tot} | total power dissipation | | | $T_C = 25^\circ\text{C}$ | | 46 | W |
| I_{FSM} | max. forward surge current | t = 10 ms; (50 Hz), sine | $T_{VJ} = 45^\circ\text{C}$ | | | 750 | A |
| | | t = 8,3 ms; (60 Hz), sine | $V_R = 0\text{ V}$ | | | 810 | A |
| | | t = 10 ms; (50 Hz), sine | $T_{VJ} = 150^\circ\text{C}$ | | | 640 | A |
| | | t = 8,3 ms; (60 Hz), sine | $V_R = 0\text{ V}$ | | | 690 | A |
| I^2t | value for fusing | t = 10 ms; (50 Hz), sine | $T_{VJ} = 45^\circ\text{C}$ | | | 2.82 | kA ² s |
| | | t = 8,3 ms; (60 Hz), sine | $V_R = 0\text{ V}$ | | | 2.73 | kA ² s |
| | | t = 10 ms; (50 Hz), sine | $T_{VJ} = 150^\circ\text{C}$ | | | 2.05 | kA ² s |
| | | t = 8,3 ms; (60 Hz), sine | $V_R = 0\text{ V}$ | | | 1.98 | kA ² s |
| C_J | junction capacitance | $V_R = 400\text{ V}; f = 1\text{ MHz}$ | $T_{VJ} = 25^\circ\text{C}$ | | 10 | | pF |



| Package PWS-B | | | | Ratings | | | |
|---------------|--|----------------------|------|---------|------|------|--|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit | |
| I_{RMS} | RMS current | per terminal | | | 100 | A | |
| T_{VJ} | virtual junction temperature | | -40 | | 150 | °C | |
| T_{op} | operation temperature | | -40 | | 125 | °C | |
| T_{stg} | storage temperature | | -40 | | 125 | °C | |
| Weight | | | | 193 | | g | |
| M_D | mounting torque | | 4.25 | | 5.75 | Nm | |
| M_T | terminal torque | | 2.5 | | 3.5 | Nm | |
| $d_{Spp/App}$ | creepage distance on surface striking distance through air | terminal to terminal | 11.0 | | | mm | |
| $d_{Spb/Apb}$ | | terminal to backside | 7.5 | | | mm | |
| V_{ISOL} | isolation voltage | t = 1 second | 3000 | | | V | |
| | | t = 1 minute | 2500 | | | V | |

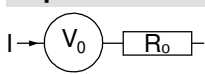


| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | VBO50-08NO7 | VBO50-08NO7 | Box | 10 | 472263 |

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 150^{\circ}C$

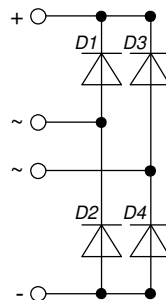
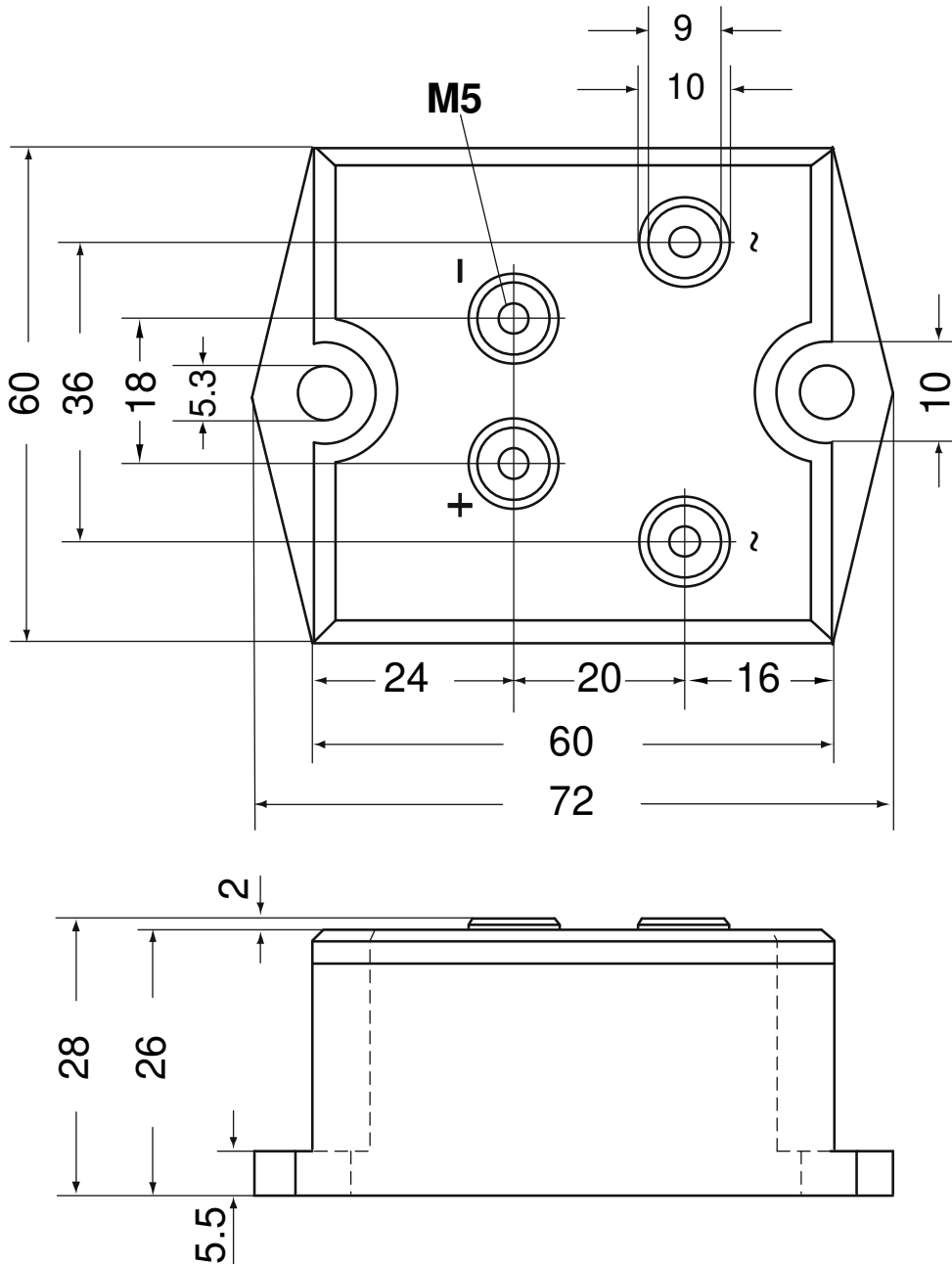


Rectifier

| | | | |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage | 0.76 | V |
| $R_{0\ max}$ | slope resistance * | 5.7 | mΩ |



Outlines PWS-B





Rectifier

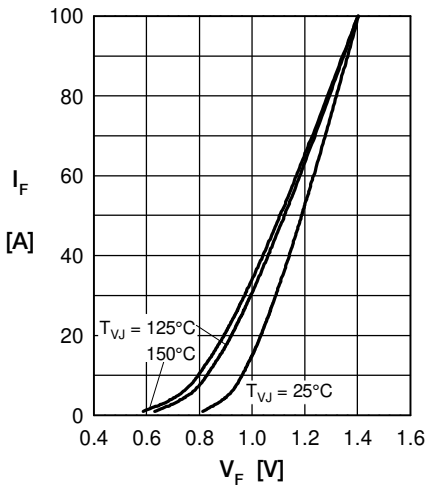


Fig. 1 Forward current vs. voltage drop per diode

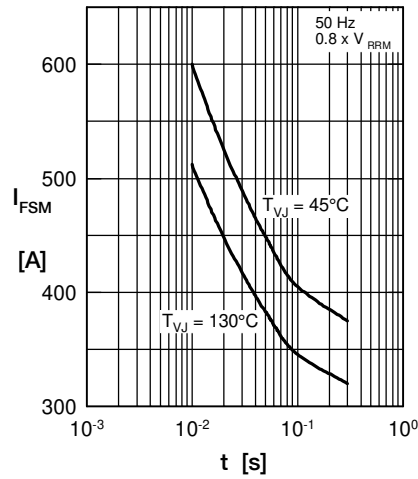


Fig. 2 Surge overload current vs. time per diode

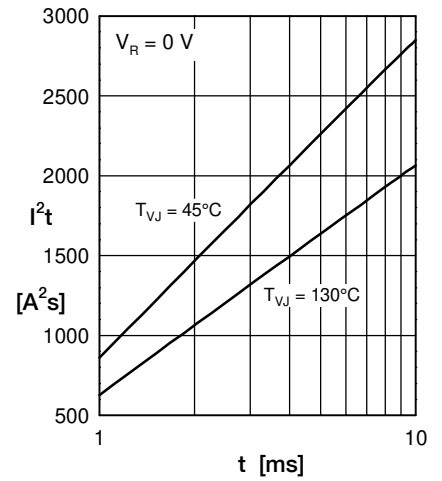


Fig. 3 I^2t vs. time per diode

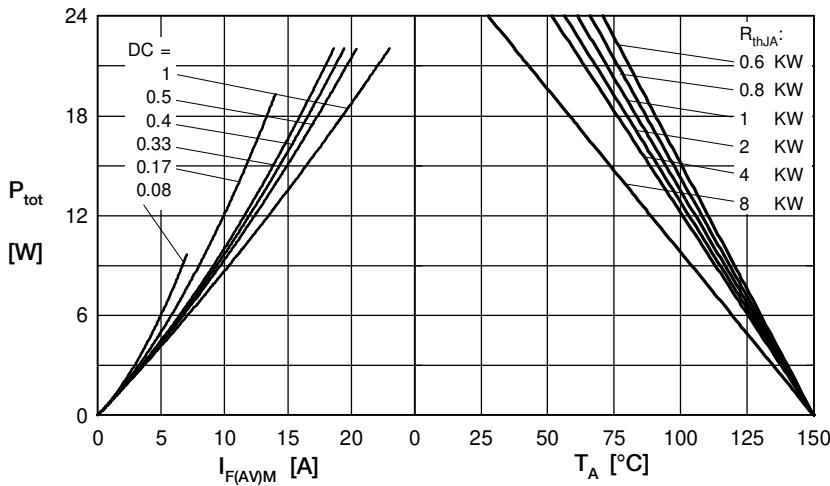


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

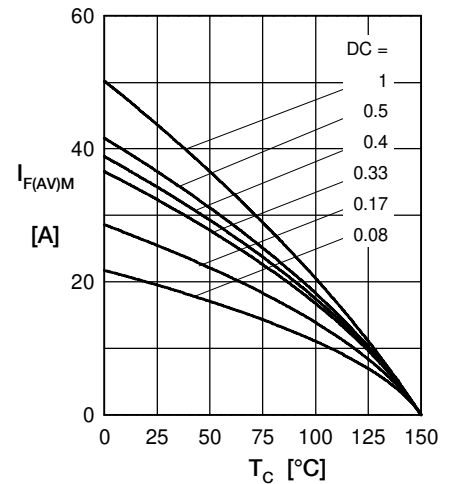


Fig. 5 Max. forward current vs. case temperature per diode

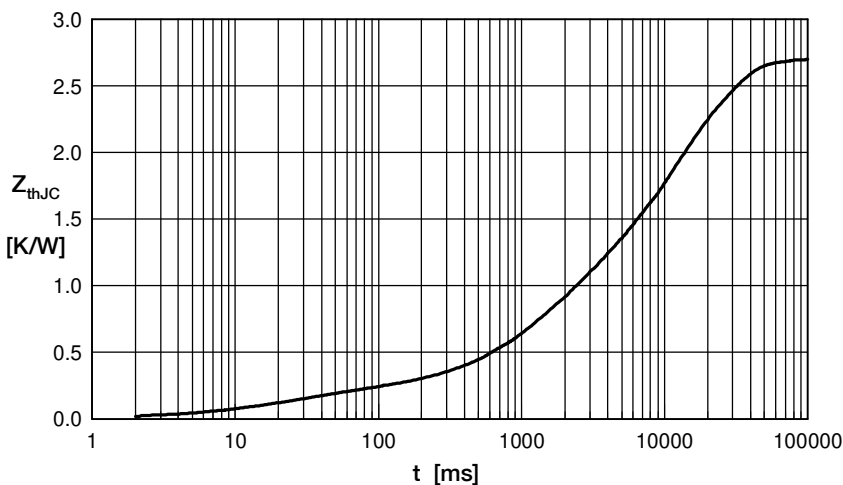


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for Z_{thJC} calculation:

| i | R_{th} (K/W) | t_i (s) |
|---|----------------|-----------|
| 1 | 0.040 | 0.010 |
| 2 | 0.150 | 0.030 |
| 3 | 0.610 | 1.350 |
| 4 | 1.900 | 14.00 |